



CBCS SCHEME

USN

--	--	--	--	--	--	--	--	--	--

15EC32

Third Semester B.E. Degree Examination, June/July 2023 Analog Electronics

Time: 3 hrs.

Max. Marks: 80

Note: Answer any FIVE full questions, choosing ONE full question from each module.

Module-1

- a. Derive the expression for Z_{in} , Z_o , A_V and A_I for voltage divider bias CE amplifier with R_E bypassed using r_e model. (10 Marks)
b. Write an explanatory note on hybrid π model. (06 Marks)

OR

- a. For an emitter bias circuit with $R_B = 470 \text{ K}\Omega$, $R_C = 2.2 \text{ K}\Omega$, $R_E = 0.56 \text{ K}\Omega$, $C_{C1} = C_{C2} = 10 \text{ }\mu\text{F}$, $h_{fe} = 120$, $r_o = 40 \text{ K}\Omega$ and $V_{CC} = 20 \text{ V}$. Find r_e , A_V , Z_{in} and Z_o if R_E is bypassed. Also write the hybrid model. (08 Marks)
b. Derive the expression for Z_{in} , Z_o , A_V and A_I for common collector configuration amplifier using approximate hybrid model. (08 Marks)

Module-2

- a. Explain the working principle of JFET. Determine JFET parameters from characteristics. (06 Marks)
b. Derive an expression for output resistance and voltage gain of fixed bias FET amplifier. (06 Marks)
c. Calculate the voltage gain of a self biased FET amplifier. The circuit uses $R_D = 2 \text{ K}\Omega$, $R_S = 1 \text{ K}\Omega$, $r_d = 40 \text{ K}\Omega$, $g_m = 2 \text{ mA/V}$ and $R_G = 2 \text{ M}\Omega$. (04 Marks)

OR

- a. Explain the construction and working principle of enhancement type MOSFET. (06 Marks)
b. Derive an expression for output impedance, input impedance, and voltage gain of a common gate amplifier. (07 Marks)
c. Distinguish between JFET and enhancement type MOSFET. (03 Marks)

Module-3

- a. Describe Miller effect and derive an expression for Miller input and output capacitance. (08 Marks)
b. Discuss the low frequency response of BJT amplifier and give expressions for low frequency due to input and output coupling capacitance. (08 Marks)

OR

- a. Discuss the high frequency response of FET amplifier and derive the expressions for cut-off frequencies defined by input and output circuits (f_{Hi} and f_{Ho}). (08 Marks)
b. For a CE amplifier using voltage divider bias, the circuit elements are $R_S = 1 \text{ K}\Omega$, $R_1 = 40 \text{ K}\Omega$, $R_2 = 10 \text{ K}\Omega$, $R_E = 2 \text{ K}\Omega$, $R_C = 4 \text{ K}\Omega$, $R_L = 2.2 \text{ K}\Omega$, $C_S = 10 \text{ mF}$, $C_C = 1 \text{ mF}$, $C_E = 20 \text{ mF}$, $h_{fe} = 100$, $r_o = \infty$, $V_{CC} = 20 \text{ V}$, $\beta = 100$ with the addition of $C_{\pi}(C_{bc}) = 36 \text{ PF}$, $C_{\mu}(C_{bc}) = 4 \text{ PF}$, $C_e = 1 \text{ PF}$, $C_{wi} = 6 \text{ PF}$ and $C_{wo} = 8 \text{ PF}$.
(i) Determine f_{Hi} and f_{Ho} (ii) Find f_{β} and f_T (08 Marks)

Module-4

- 7 a. Determine the input and output resistances of a voltage series feedback amplifier. (06 Marks)
 b. Briefly explain the characteristics of negative feedback amplifier. (06 Marks)
 c. An amplifier has a bandwidth of 300 kHz and voltage gain of 100. A negative feedback of 10% is introduced. Determine the gain bandwidth with feedback. Also determine the amount of feedback required if the bandwidth is limited to 800 kHz. (04 Marks)

OR

- 8 a. Explain FET phase shift oscillator with neat circuit diagram and necessary equations. (06 Marks)
 b. Explain the working of Wein bridge oscillator. (06 Marks)
 c. Calculate the oscillator frequency for an FET Hartley oscillator with tank circuit elements $C = 250 \text{ PF}$; $L_1 = 1.5 \text{ mH}$; $L_2 = 2.5 \text{ mH}$ and $M = 0.5 \text{ mH}$. (04 Marks)

Module-5

CMRIT LIBRARY
 BANGALORE - 560 037

- 9 a. Derive the expression for second harmonic distortion. (06 Marks)
 b. Discuss the classification of power amplifiers. (06 Marks)
 c. Calculate the input power, output power and efficiency of a series fed class A power amplifier with the following specifications: $V_{CC} = 20 \text{ V}$, $R_B = 1 \text{ K}\Omega$, $R_C = 20 \Omega$. The input voltage results in a base current of 10 mA peak. Assume $\beta = 25$. (04 Marks)

OR

- 10 a. Derive an expression for the conversion efficiency of class B push pull amplifier with neat circuit diagram and waveforms. (08 Marks)
 b. Define voltage regulator. Explain the series voltage regulator using transistor. (05 Marks)
 c. Calculate the Total Harmonic Distortion (THD), fundamental power component and total power given $D_2 = 0.1$, $D_3 = 0.02$, $D_4 = 0.01$ with $I_1 = 4 \text{ A}$ and $R_C = 8 \Omega$. (03 Marks)
